Diode Semiconductor Device - Page 1 of 1



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Gla	ass
Ov	erall Length:
0.3	75 inches
Те	rminal Length:
1.0	00 inches
Ov	erall Diameter:
0.2	34 inches
Мо	ounting Method:
Те	rminal
Fea	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sili	con
Vo	Itage Rating In Volts Per Characteristic:
1.9	regulator voltage
Cu	rrent Rating Per Characteristic:
20.	00 milliamperes repetitive peak forward current
Ма	ximum Operating Tempurature Per Measurement Point:
150	0.0 degrees celsius ambient air
Tei	rminal Type And Quantity:
2 u	ninsulated wire lead
Sh	elf Life:
N/a	a de la construcción de la constru
Un	it Of Measure:
De	militarization:
No	
Fiig	g:
A1	10a0